

CMOS Logic

■ GENERAL DESCRIPTION

XC74WL125ASR is dual bus buffer manufactured using silicon gate CMOS processes. The small supply current, which is one of the features of the CMOS logic, gives way to high speed operations which enables LS-TTL.

With wave forming buffers connected internally, stabilized output can be achieved as the series offers high noise immunity.

As the series is integrated into a mini molded, MSOP-8B package, high density mounting is possible.

■ APPLICATIONS

- Palmtops
- Digital equipment

■ FEATURES

High Speed Operations : $t_{pd} = 3.8\text{ns}$ (TYP.) ($V_{CC}=5\text{V}$)

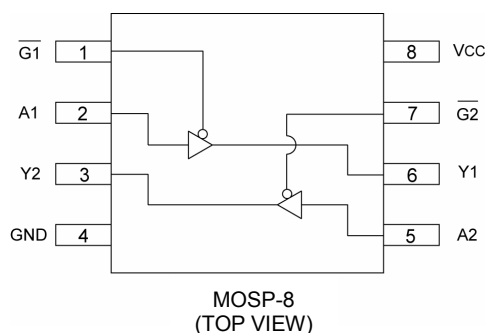
Operating Voltage Range : $2\text{V} \sim 5.5\text{V}$

Low Power Consumption: $2\mu\text{A}$ (MAX.)

CMOS Logic Dual Bus Buffer

Small Package : MSOP-8B

■ PIN CONFIGURATION



■ FUNCTIONS

INPUT		OUTPUT
$\overline{G}$	A	Y
H	X	Z
L	H	H
L	L	L

H=High level

L=Low level

X=Don't care

Z=High impedance

■ ABSOLUTE MAXIMUM RATINGS

$T_a = -40^\circ\text{C} \sim 85^\circ\text{C}$

PARAMETER	SYMBOL	RATINGS	UNITS
Supply Voltage	V_{CC}	$-0.5 \sim +6.0$	V
Input Voltage	V_{IN}	$-0.5 \sim +6.0$	V
Output Voltage	V_{OUT}	$-0.5 \sim V_{CC} + 0.5$	V
Input Diode Current	I_{IK}	-20	mA
Output Diode Current	I_{OK}	± 20	mA
Output Current	I_{OUT}	± 25	mA
V_{CC}, GND Current	I_{CC}, I_{GND}	± 50	mA
Power Dissipation ($T_a = 25^\circ\text{C}$)	P_d	300	mW
Storage Temperature Range	T_{stg}	$-65 \sim +150$	$^\circ\text{C}$

Note : Voltage is all ground standardized.

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	CONDITIONS	UNITS
Supply Voltage	V _{CC}	2~5.5	V
Input Voltage	V _{IN}	0~5.5	V
Output Voltage	V _{OUT}	0~ V _{CC}	V
Operating Temperature Range	T _{opr}	-40~+85	°C
Input Rise and Fall Time	tr,tf	0~200 (V _{CC} =3.3V)	ns
		0~100 (V _{CC} =5V)	

DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	V _{CC} (V)	CONDITIONS	Ta=25°C			Ta=-40°C~85°C		UNITS
				MIN.	TYP.	MAX.	MIN.	MAX.	
Input Voltage	V _{IH}	2.0		1.50	—	—	1.50	—	V
		3.0		2.10	—	—	2.10	—	
		5.5		3.85	—	—	3.85	—	
	V _{IL}	2.0		—	—	0.50	—	0.50	V
		3.0		—	—	0.90	—	0.90	
		5.5		—	—	1.65	—	1.65	
Output Voltage	V _{OH}	2.0	V _{IN} =V _{IH}	I _{OH} =-50 μA	1.90	2.00	—	1.90	V
		3.0			2.90	3.00	—	2.90	
		4.5			4.40	4.50	—	4.40	
		3.0			2.58	—	—	2.48	
		4.5			3.94	—	—	3.80	
	V _{OL}	2.0	V _{IN} =V _{IL}	I _{OL} =50 μA	—	—	0.10	—	V
		3.0			—	—	0.10	—	
		4.5			—	—	0.10	—	
		3.0		I _{OL} =4mA	—	—	0.36	—	
		4.5		I _{OL} =8mA	—	—	0.36	—	
3 State Off-Leak Current	I _{OZ}	5.0	V _{IN} =V _{IL} or V _{IH} , V _{OUT} =V _{CC} or GND	-0.25	—	0.25	-2.50	2.50	μA
Input Current	I _{IN}	0~5.5	V _{IN} =V _{CC} or GND	-0.10	—	0.1	-1.00	1.00	μA
Static Supply Current	I _{CC}	5.5	V _{IN} =V _{CC} or GND	—	—	2.0	—	20.0	μA

SWITCHING ELECTRICAL CHARACTERISTICS

(tr=tf=3ns)

PARAMETER	SYMBOL	V _{CC} (V)	CONDITIONS	Ta=25°C			Ta=-40°C~85°C		UNITS
				MIN.	TYP.	MAX.	MIN.	MAX.	
Delay Time	t _{PLH}	3.3	C _L =15pF	—	5.6	8.0	1.0	9.5	ns
		5.0		—	3.8	5.5	1.0	6.5	
		3.3	C _L =50pF	—	8.1	11.5	1.0	13.0	ns
		5.0		—	5.3	7.5	1.0	8.5	
	t _{PHL}	3.3	C _L =15pF	—	5.6	8.0	1.0	9.5	ns
		5.0		—	3.8	5.5	1.0	6.5	
		3.3	C _L =50pF	—	8.1	11.5	1.0	13.0	ns
		5.0		—	5.3	7.5	1.0	8.5	
Output Enable Time	t _{ZL}	3.3	R _L =1kΩ	—	5.4	8.0	1.0	9.5	ns
		5.0	C _L =15pF	—	3.6	5.1	1.0	6.0	
		3.3	R _L =1kΩ	—	7.9	11.5	1.0	13	ns
		5.0	C _L =50pF	—	5.1	7.1	1.0	8.0	
	t _{ZH}	3.3	R _L =1kΩ	—	5.4	8.0	1.0	9.5	ns
		5.0	C _L =15pF	—	3.6	5.1	1.0	6.0	
		3.3	R _L =1kΩ	—	7.9	11.5	1.0	13.0	ns
		5.0	C _L =50pF	—	5.1	7.1	1.0	8.0	
Output Disable Time	t _{LZ}	3.3	R _L =1kΩ	—	9.5	13.2	1.0	15.0	ns
		5.0	C _L =50pF	—	6.1	8.8	1.0	10.0	
	t _{HZ}	3.3	R _L =1kΩ	—	9.5	13.2	1.0	15.0	ns
		5.0	C _L =50pF	—	6.1	8.8	1.0	10.0	
Output Pin Skew (Note)	t _{OSLH}	3.3	C _L =50pF	—	—	1.5	—	1.5	ns
		5.0		—	—	1.0	—	1.0	
	t _{OSHL}	3.3	C _L =50pF	—	—	1.5	—	1.5	ns
		5.0		—	—	1.0	—	1.0	
Input Capacitance	C _{IN}	—		—	4	10	—	10	pF
Output Capacitance	C _{OUT}	—		—	6	—	—	—	pF
Power Dissipation Capacitance	C _{pd}	—		—	14	—	—	—	pF

Note: t_{OSLH} and t_{OSHL} are the guaranteed parameters.

$$t_{OSLH} = |t_{PLHm} - t_{PHLn}|, \quad t_{OSHL} = |t_{PHLm} - t_{PLLn}|$$

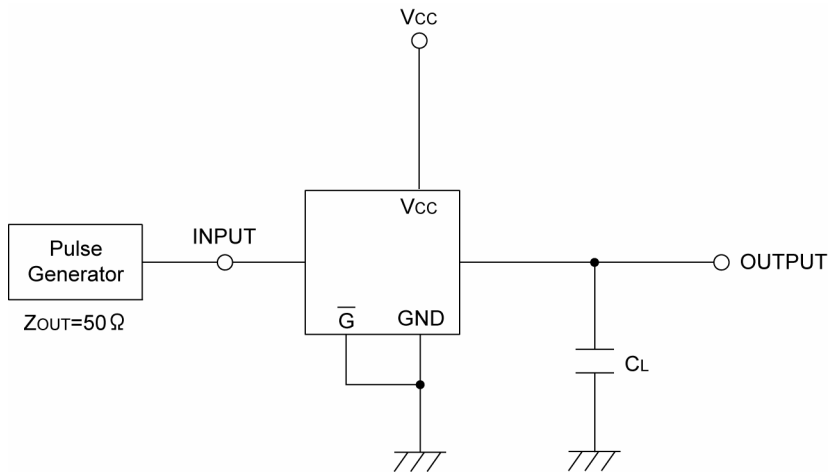
NOISE CHARACTERISTICS

(tr=tf=3ns)

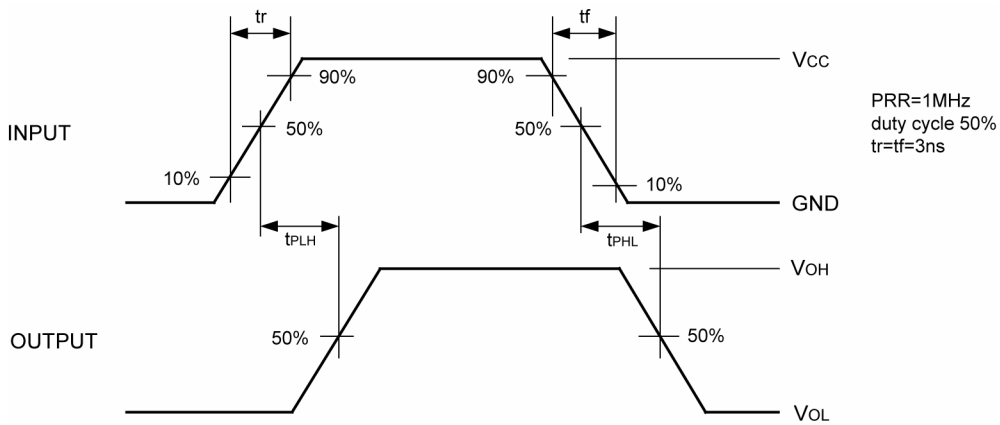
PARAMETER	SYMBOL	CONDITIONS		Ta=25°C			UNITS
		C _L	V _{CC} (V)	MIN.	TYP.	MAX.	
Non Functional Output Maximum Dynamic V _{OL}	V _{OLP}	50pF	5.0	—	0.3	0.8	V
Non Functional Output Minimum Dynamic V _{OL}	V _{OLV}	50pF	5.0	-0.8	-0.3	—	V
Minimum Dynamic V _{IH}	V _{IHD}	50pF	5.0	—	—	3.5	V
Maximum Dynamic V _{IL}	V _{ILD}	50pF	5.0	—	—	1.5	V

■ DELAY TIME

● Test Circuit

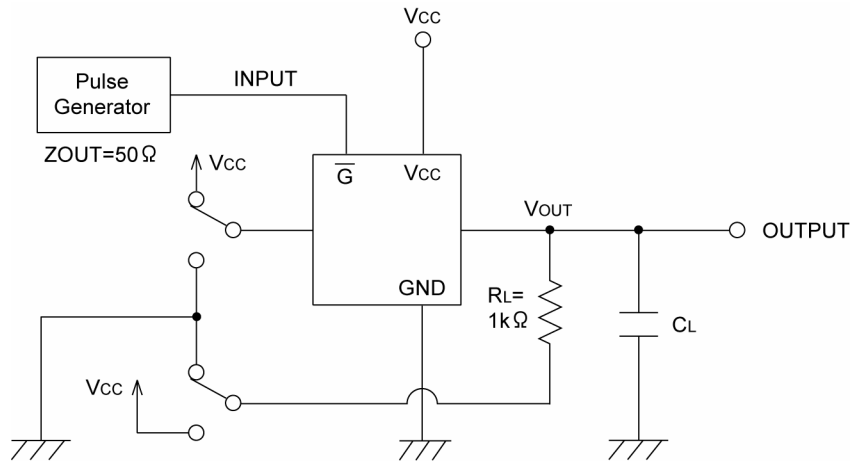


● Waveform

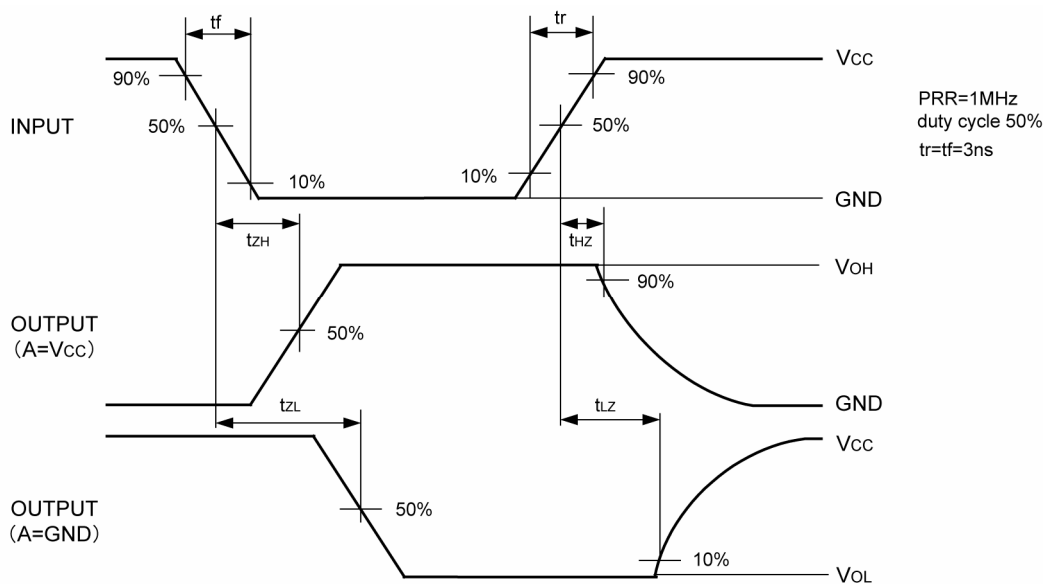


■ OUTPUT ENABLE TIME, OUTPUT DISABLE TIME

● Test Circuit



● Waveform



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